



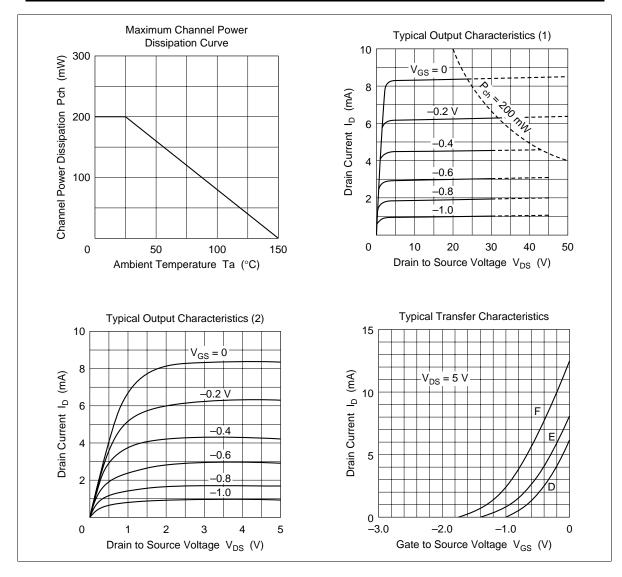


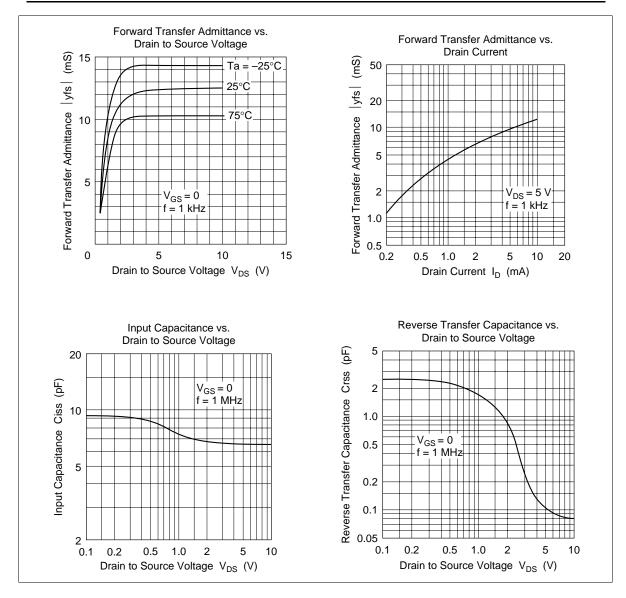
Absolute Maximum Ratings (Ta = 25° C)

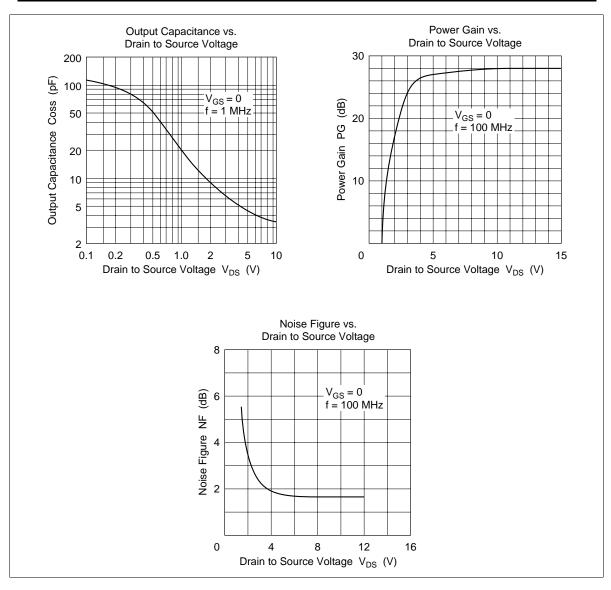
Item	Symbol	Ratings	Unit	
Gate to drain voltage	V_{gdo}	-30	V	
Gate current	Ι _G	10	mA	
Drain current	I _D	20	mA	
Channel power dissipation	Pch	200	mW	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

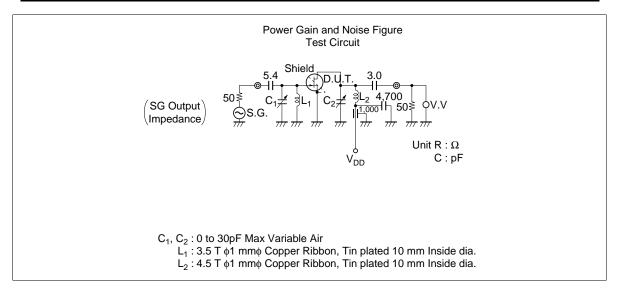
Electrical Characteristics (Ta = 25° C)

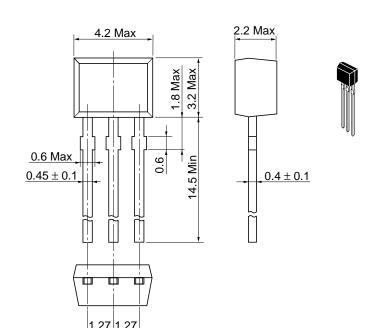
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Gate to drain breakdown voltage	$V_{(\text{BR})\text{GDO}}$	-30	_	_	V	$I_{\rm G} = -100 \ \mu \text{A}, \ I_{\rm S} = 0$
Gate cutoff current	I _{GSS}	_	_	-10	nA	$V_{GS} = -0.5 \text{ V}, V_{DS} = 0$
Drain current	I*1	4	_	20	mA	$V_{\rm DS} = 5 V, V_{\rm GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	—	_	-3	V	V_{DS} = 5 V, I_{D} = 10 μ A
Forward transfer admittance	y _{fs}	8	10	_	mS	$V_{DS} = 5 V, V_{GS} = 0, f = 1 \text{ kHz}$
Input capacitance	Ciss	—	6.8		pF	$V_{DS} = 5 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$
Reverse transfer capacitance	Crss	—	0.1		pF	
Power gain	PG	20	27	_	dB	$V_{DS} = 5 V, V_{GS} = 0,$ f = 100 MHz
Noise figure	NF	_	1.7	2.5	dB	
Note: 1. The 2SK522 is grouped by I _{DSS} as follows.						
Drain D E		F				
I _{DSS} 4 to 8 6	to 10	10 to 2	20			











Unit: mm

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